

Flange Mount Termination 150 Watts, 50 Ω



Features:

- **RoHS Compliant**
- 150 Watts
- DC 3.0 GHz
- **AIN Ceramic**
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Outline Drawing

Description

The G150N50W4E is high performance Aluminum Nitride (AIN) flange mount termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element	Thick Film
Substrate	AIN Ceramic
Mounting Flange	Nickel Plated Copper
Operating Temperature	-50 to +150°C (see de rating chart)
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.	

Electrical Specifications

Resistance Value:	50 Ohms, ± 2%
Power:	150 Watts
Frequency Range:	DC – 3.0 GHz
Return Loss	25dB DC – 2.0 GHz
	20dB DC – 3.0 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**





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Typical Performance:









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